

3A, 50V - 1000V Glass Passivated Rectifier

FEATURES

- Glass passivated chip junction
- High current capability, Low V_F
- High reliability
- High surge current capability
- Low power loss, high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer and telecommunication.

MECHANICAL DATA

- Case: DO-201AD
- Molding compound meets UL 94V-0 flammability rating
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 1.2 g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
$I_{F(AV)}$	3	A
V_{RRM}	50 - 1000	V
I_{FSM}	125	A
$T_{J\ MAX}$	150	°C
Package	DO-201AD	
Configuration	Single Die	



DO-201AD

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)									
PARAMETER	SYMBOL	1N5400 G-K	1N5401 G-K	1N5402 G-K	1N5404 G-K	1N5406 G-K	1N5407 G-K	1N5408 G-K	UNIT
Marking code on the device		1N5400G	1N5401G	1N5402G	1N5404G	1N5406G	1N5407G	1N5408G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Forward current	$I_{F(AV)}$	3							A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	125							A
Junction temperature	T_J	- 55 to +150							°C
Storage temperature	T_{STG}	- 55 to +150							°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient thermal resistance	$R_{\theta JA}$	45	°C/W
Junction-to-case thermal resistance	$R_{\theta JC}$	15	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 3A, T_J = 25^\circ\text{C}$	V_F	-	1.1	V
			-	1.0	V
			-	-	-
			-	-	-
			-	-	-
			-	-	-
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	5	μA
	$T_J = 125^\circ\text{C}$		-	100	μA
Junction capacitance	1 MHz, $V_R = 4.0\text{V}$	C_J	25	-	pF

Notes:

1. Pulse test with $PW = 0.3\text{ ms}$
2. Pulse test with $PW = 30\text{ ms}$

ORDERING INFORMATION

PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
1N540xG-K (Note 1, 2)	A0	G	DO-201AD	500 / Ammo box
	R0		DO-201AD	1,250 / 13" Paper reel
	B0		DO-201AD	500 / Bulk packing

Notes:

1. "x" defines voltage from 50V (1N5400G-K) to 1000V (1N5408G-K)
2. Whole series with green compound (halogen-free)

EXAMPLE P/N

EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
1N5400G-K A0G	1N5400G-K	A0	G	Green compound

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

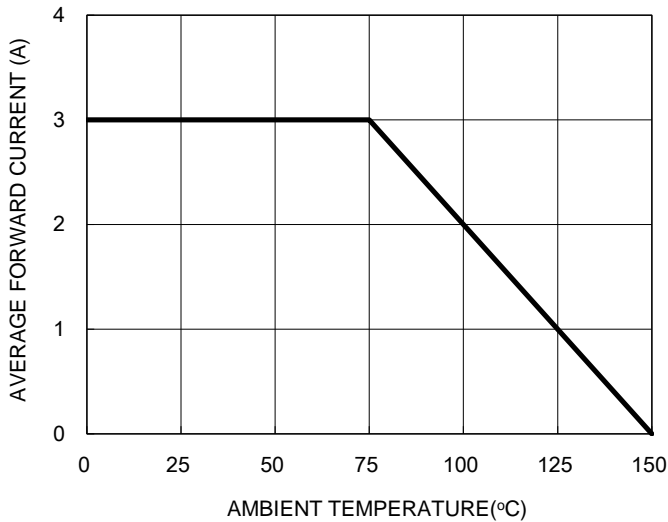


Fig.2 Typical Junction Capacitance

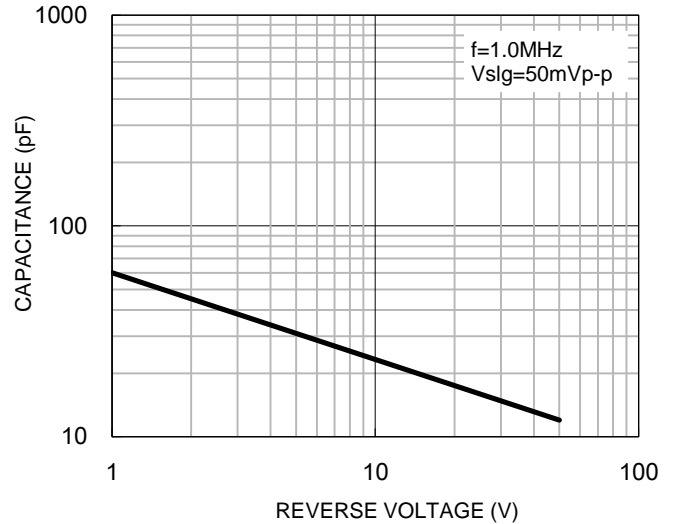


Fig.3 Typical Reverse Characteristics

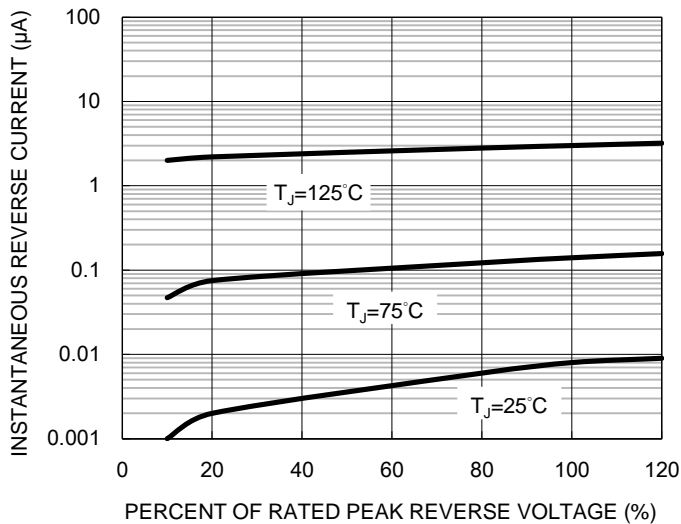
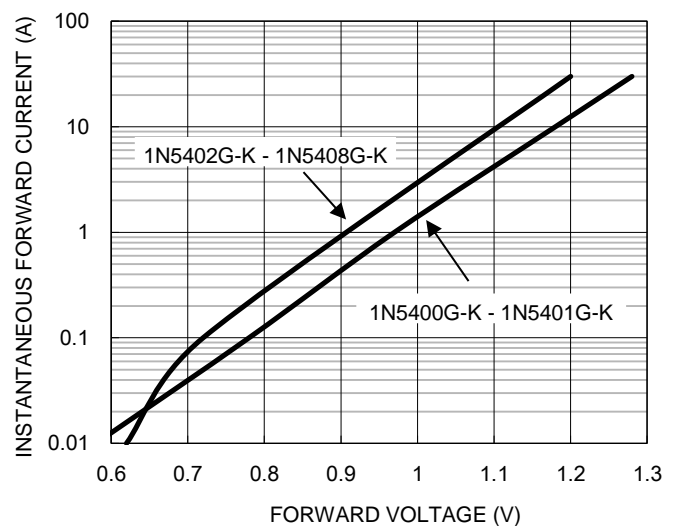


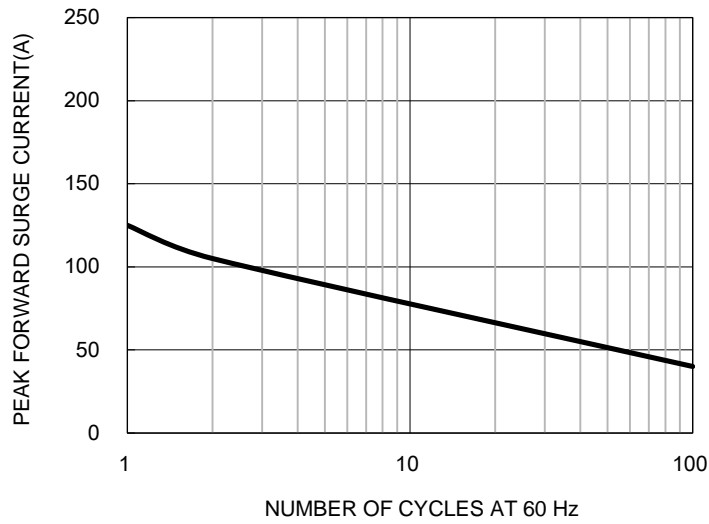
Fig.4 Typical Forward Characteristics



CHARACTERISTICS CURVES

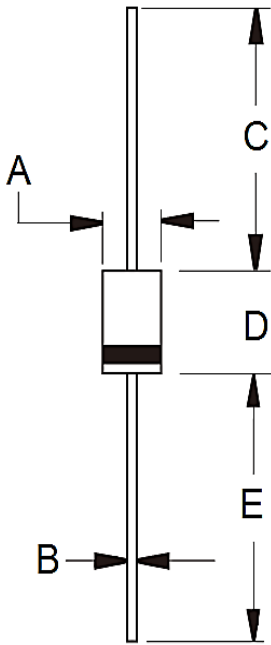
($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.5 Maximum Non-repetitive Forward Surge Current



PACKAGE OUTLINE DIMENSIONS

DO-201AD



DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	5.00	5.60	0.197	0.220
B	1.20	1.30	0.048	0.052
C	25.40	-	1.000	-
D	8.50	9.50	0.335	0.375
E	25.40	-	1.000	-

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code

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